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FDP5N60NZ / FDPF5N60NZ N-Channel UniFET™ II MOSFET 600 V, 4.5 A, 2.0 Ω

Features

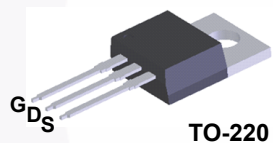
- $R_{DS(on)} = 1.65 \Omega$ (Typ.) @ $V_{GS} = 10 V$, $I_D = 2.25 A$
- Low Gate Charge (Typ. 10 nC)
- Low C_{rss} (Typ. 5 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability
- ESD Improved Capability
- RoHS Compliant

Applications

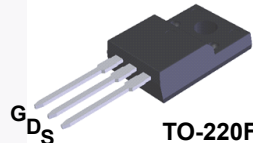
- LCD / LED / PDP TV
- Lighting
- Uninterruptible Power Supply
- AC-DC Power Supply

Description

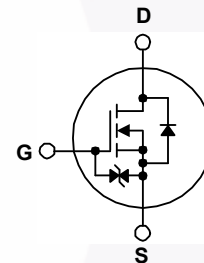
UniFET™ II MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on advanced planar stripe and DMOS technology. This advanced MOSFET family has the smallest on-state resistance among the planar MOSFET, and also provides superior switching performance and higher avalanche energy strength. In addition, internal gate-source ESD diode allows UniFET II MOSFET to withstand over 2kV HBM surge stress. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



TO-220



TO-220F



MOSFET Maximum Ratings $T_C = 25^\circ C$ unless otherwise noted.

Symbol	Parameter	FDP5N60NZ	FDPF5N60NZ	Unit
V_{DSS}	Drain to Source Voltage	600		V
V_{GSS}	Gate to Source Voltage	±25		V
I_D	Drain Current	- Continuous ($T_C = 25^\circ C$)	4.5	4.5*
		- Continuous ($T_C = 100^\circ C$)	2.7	2.7*
I_{DM}	Drain Current	- Pulsed (Note 1)	18	18*
E_{AS}	Single Pulsed Avalanche Energy	(Note 2)	175	mJ
I_{AR}	Avalanche Current	(Note 1)	4.5	A
E_{AR}	Repetitive Avalanche Energy	(Note 1)	10	mJ
dv/dt	MOSFET dv/dt		20	V/ns
	Peak Diode Recovery dv/dt	(Note 3)	10	V/ns
P_D	Power Dissipation	($T_C = 25^\circ C$)	100	33
		- Derate above $25^\circ C$	0.8	0.27
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to +150		$^\circ C$
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds	300		$^\circ C$

*Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FDP5N60NZ	FDPF5N60NZ	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.25	3.75	$^\circ C/W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	62.5	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDP5N60NZ	FDP5N60NZ	TO-220	Tube	N/A	N/A	50 units
FDPF5N60NZ	FDPF5N60NZ	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250\ \mu\text{A}$, $V_{GS} = 0\ \text{V}$	600	-	-	V
$\Delta BV_{DSS} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$, Referenced to 25°C	-	0.6	-	$\text{V}/^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 600\ \text{V}$, $V_{GS} = 0\ \text{V}$	-	-	1	μA
		$V_{DS} = 480\ \text{V}$, $T_C = 125^\circ\text{C}$	-	-	10	
I_{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 25\ \text{V}$, $V_{DS} = 0\ \text{V}$	-	-	± 10	μA

On Characteristics

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250\ \mu\text{A}$	3.0	-	5.0	V
$R_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10\ \text{V}$, $I_D = 2.25\ \text{A}$	-	1.65	2.0	Ω
g_{FS}	Forward Transconductance	$V_{DS} = 20\ \text{V}$, $I_D = 2.25\ \text{A}$	-	5	-	S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 25\ \text{V}$, $V_{GS} = 0\ \text{V}$, $f = 1\ \text{MHz}$	-	450	600	pF
C_{oss}	Output Capacitance		-	50	65	pF
C_{rss}	Reverse Transfer Capacitance		-	5	7.5	pF
Q_g	Total Gate Charge at 10V	$V_{DS} = 480\ \text{V}$, $I_D = 4.5\ \text{A}$, $V_{GS} = 10\ \text{V}$	-	10	13	nC
Q_{gs}	Gate to Source Gate Charge		-	2.5	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		-	4	-	nC

(Note 4)

Switching Characteristics

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 300\ \text{V}$, $I_D = 4.5\ \text{A}$, $V_{GS} = 10\ \text{V}$, $R_G = 25\ \Omega$	-	15	40	ns
t_r	Turn-On Rise Time		-	20	50	ns
$t_{d(off)}$	Turn-Off Delay Time		-	35	80	ns
t_f	Turn-Off Fall Time	(Note 4)	-	20	50	ns

Drain-Source Diode Characteristics

I _S	Maximum Continuous Drain to Source Diode Forward Current		-	-	4.5	A
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	18	A
V _{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0 V, I _{SD} = 4.5 A	-	-	1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _{SD} = 4.5 A, dI _F /dt = 100 A/μs	-	230	-	ns
Q _{rr}	Reverse Recovery Charge		-	0.9	-	μC

Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. $L = 17.3\ \text{mH}$, $I_{AS} = 4.5\ \text{A}$, $V_{DD} = 50\ \text{V}$, $R_G = 25\ \Omega$, starting $T_J = 25^\circ\text{C}$.
3. $I_{SD} \leq 4.5\ \text{A}$, $di/dt \leq 200\ \text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, starting $T_J = 25^\circ\text{C}$.
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

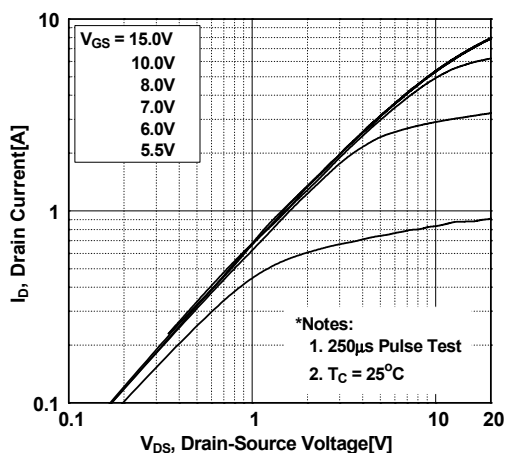


Figure 2. Transfer Characteristics

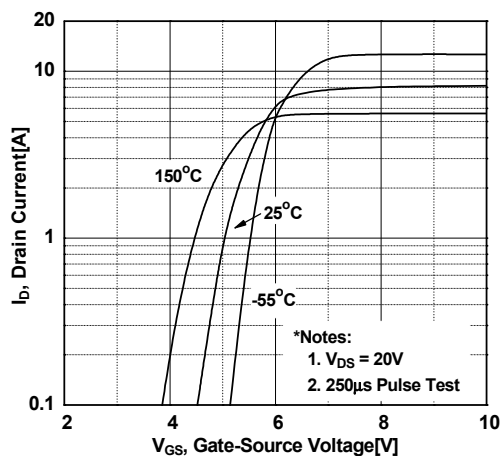


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

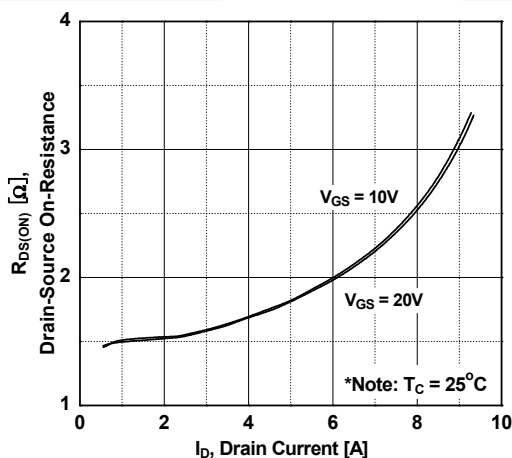


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

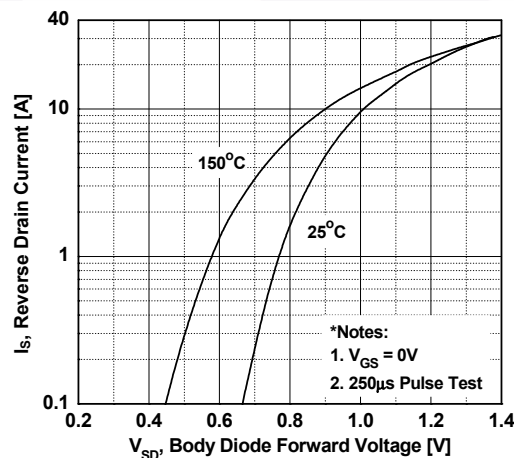


Figure 5. Capacitance Characteristics

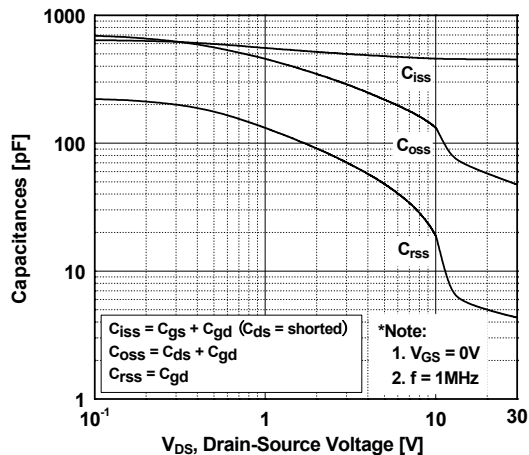
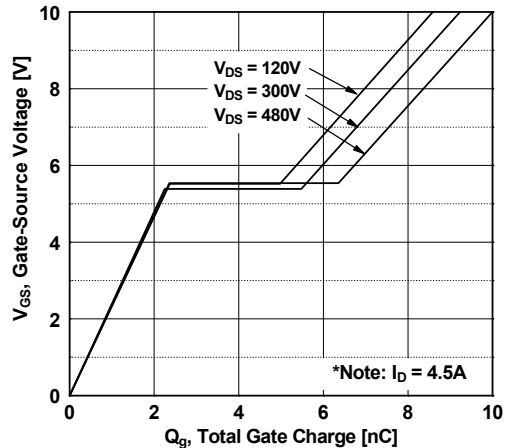


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

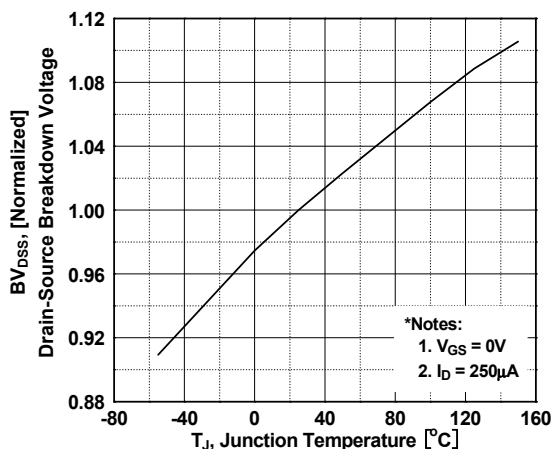


Figure 8. On-Resistance Variation vs. Temperature

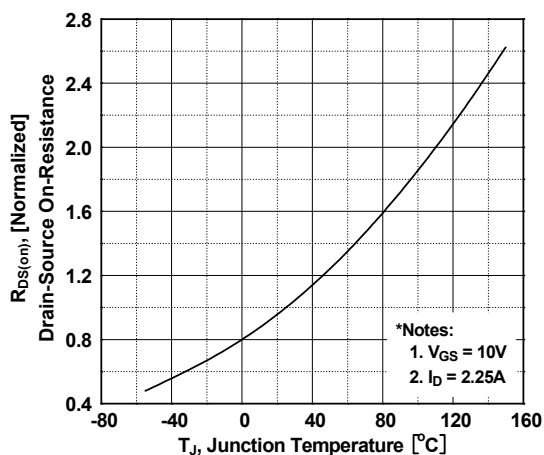


Figure 9. Maximum Safe Operating Area - FDP5N60NZ

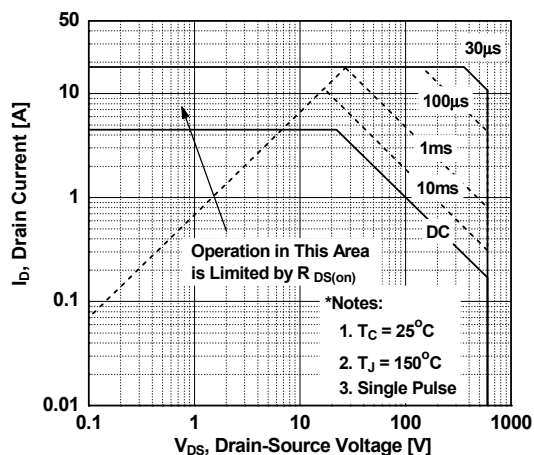


Figure 10. Maximum Safe Operating Area - FDPF5N60NZ

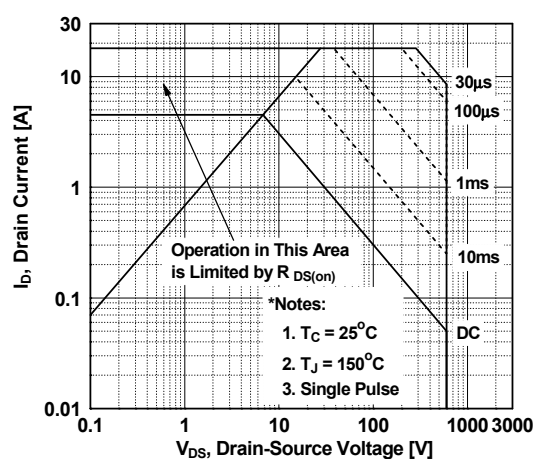


Figure 11. Maximum Drain Current vs. Case Temperature

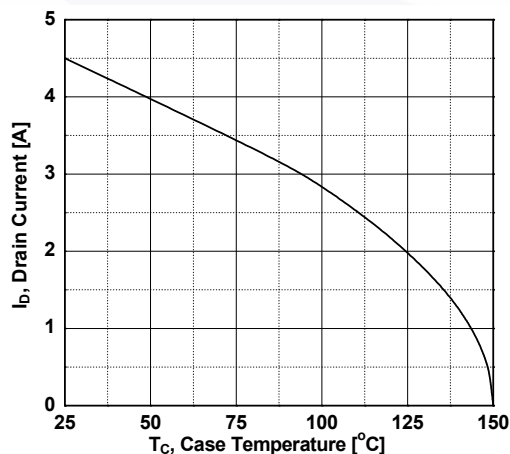
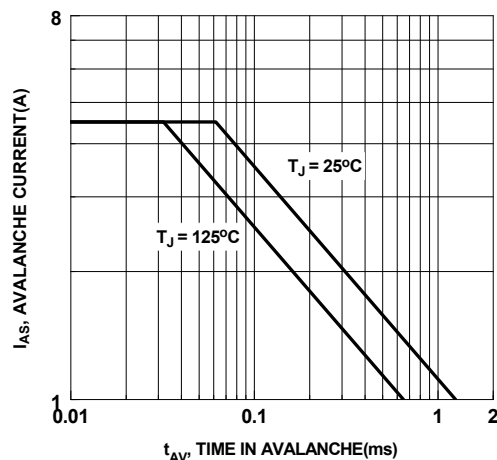


Figure 12. Unclamped Inductive Switching Capability



Typical Performance Characteristics (Continued)

Figure 13. Transient Thermal Response Curve - FDP5N60NZ

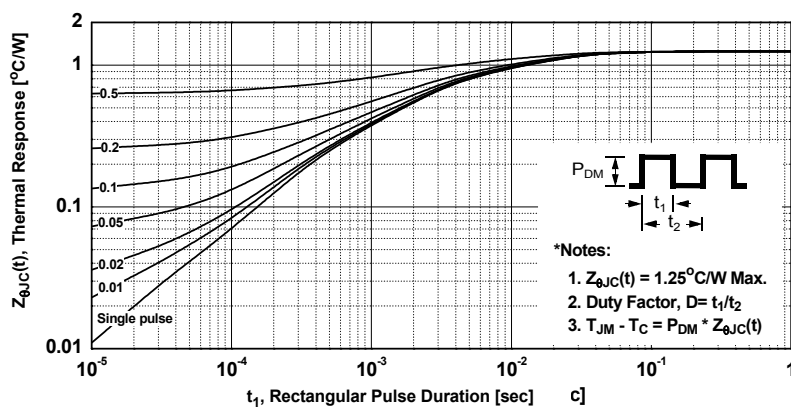
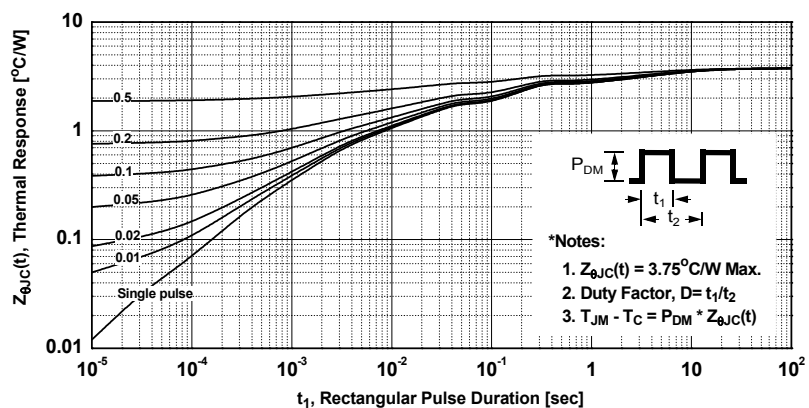


Figure 14. Transient Thermal Response Curve - FDPF5N60NZ



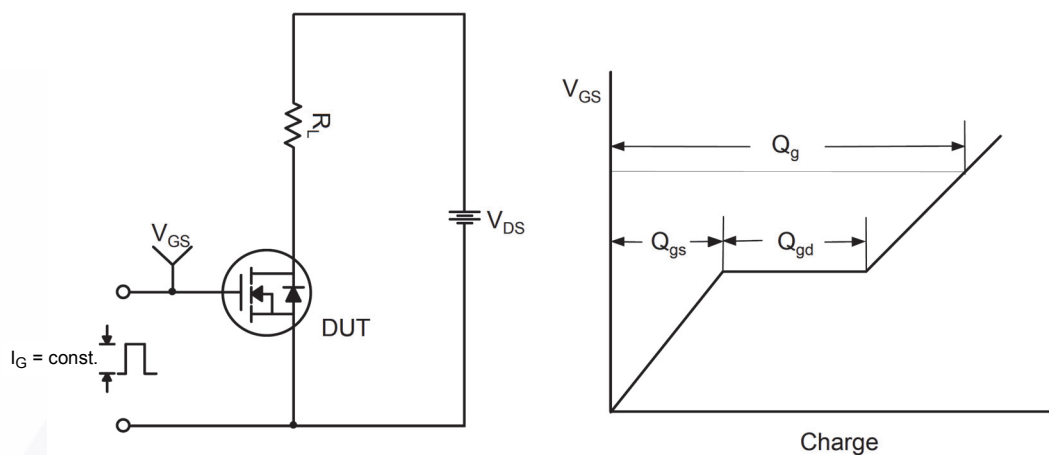


Figure 15. Gate Charge Test Circuit & Waveform

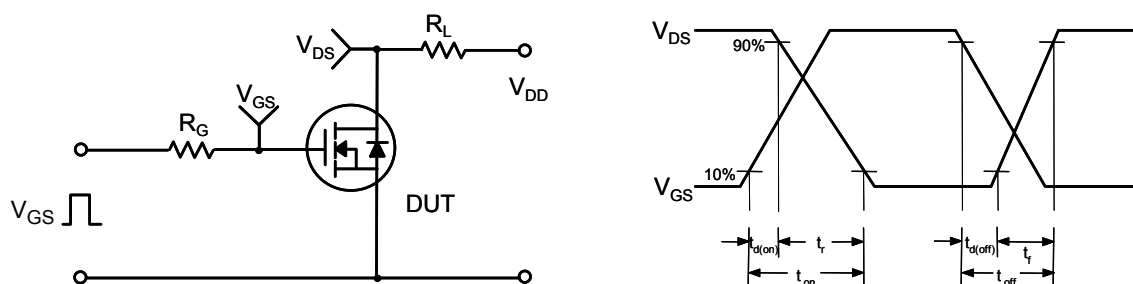


Figure 16. Resistive Switching Test Circuit & Waveforms

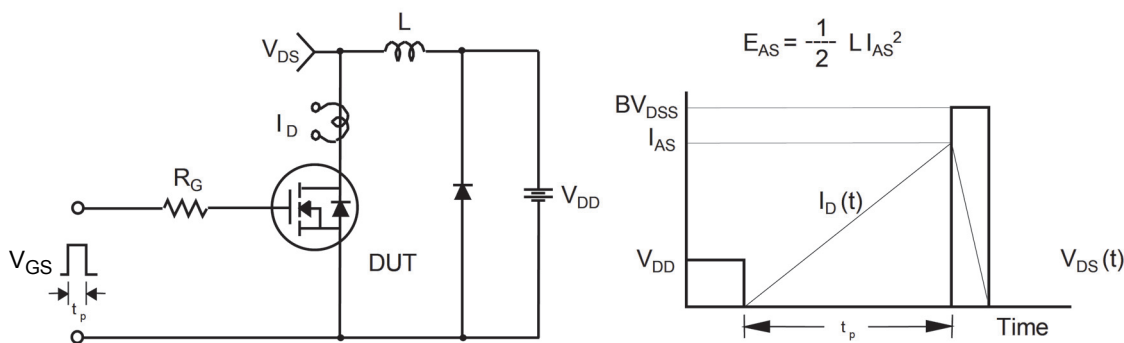


Figure 17. Unclamped Inductive Switching Test Circuit & Waveforms

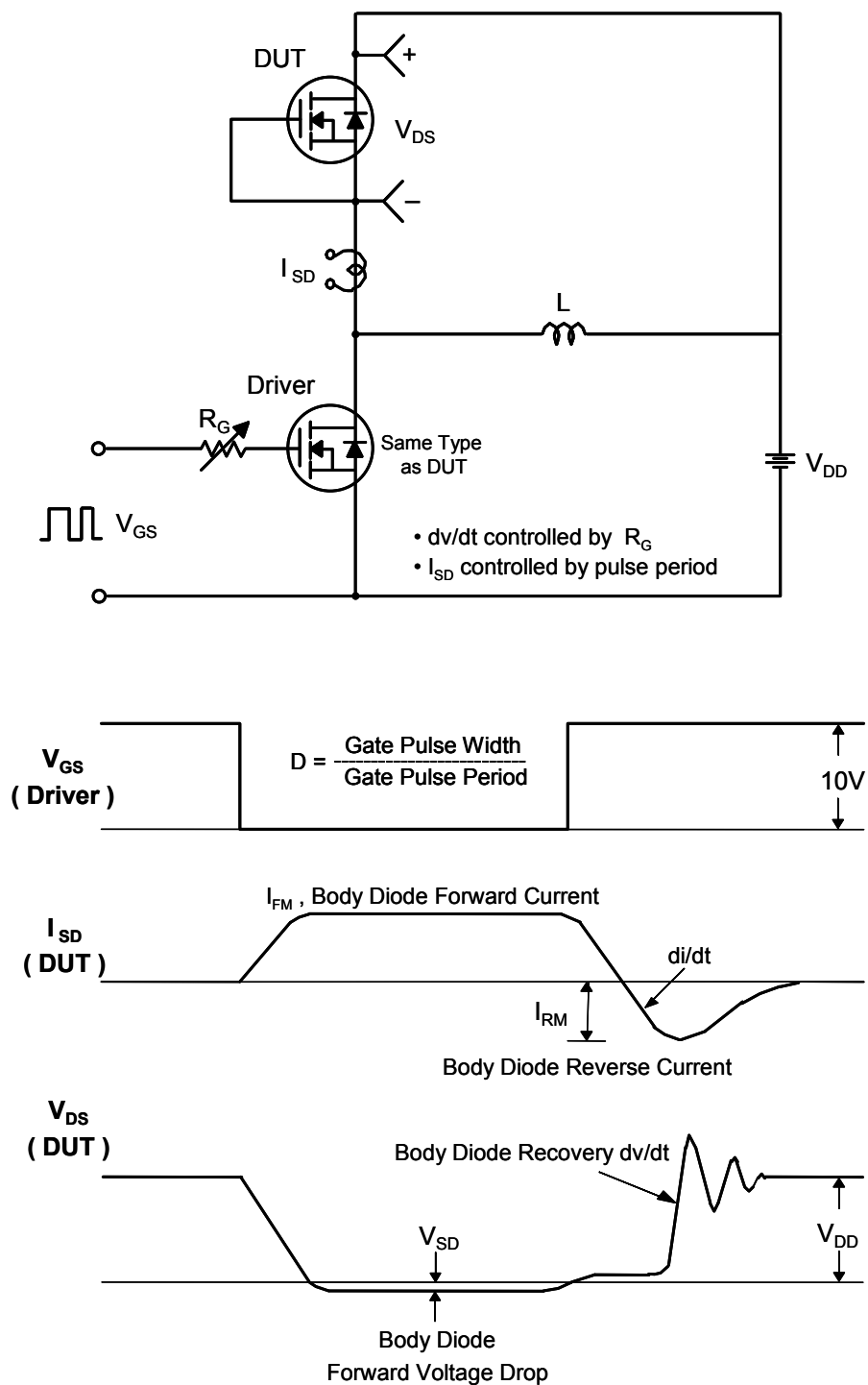


Figure 18. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

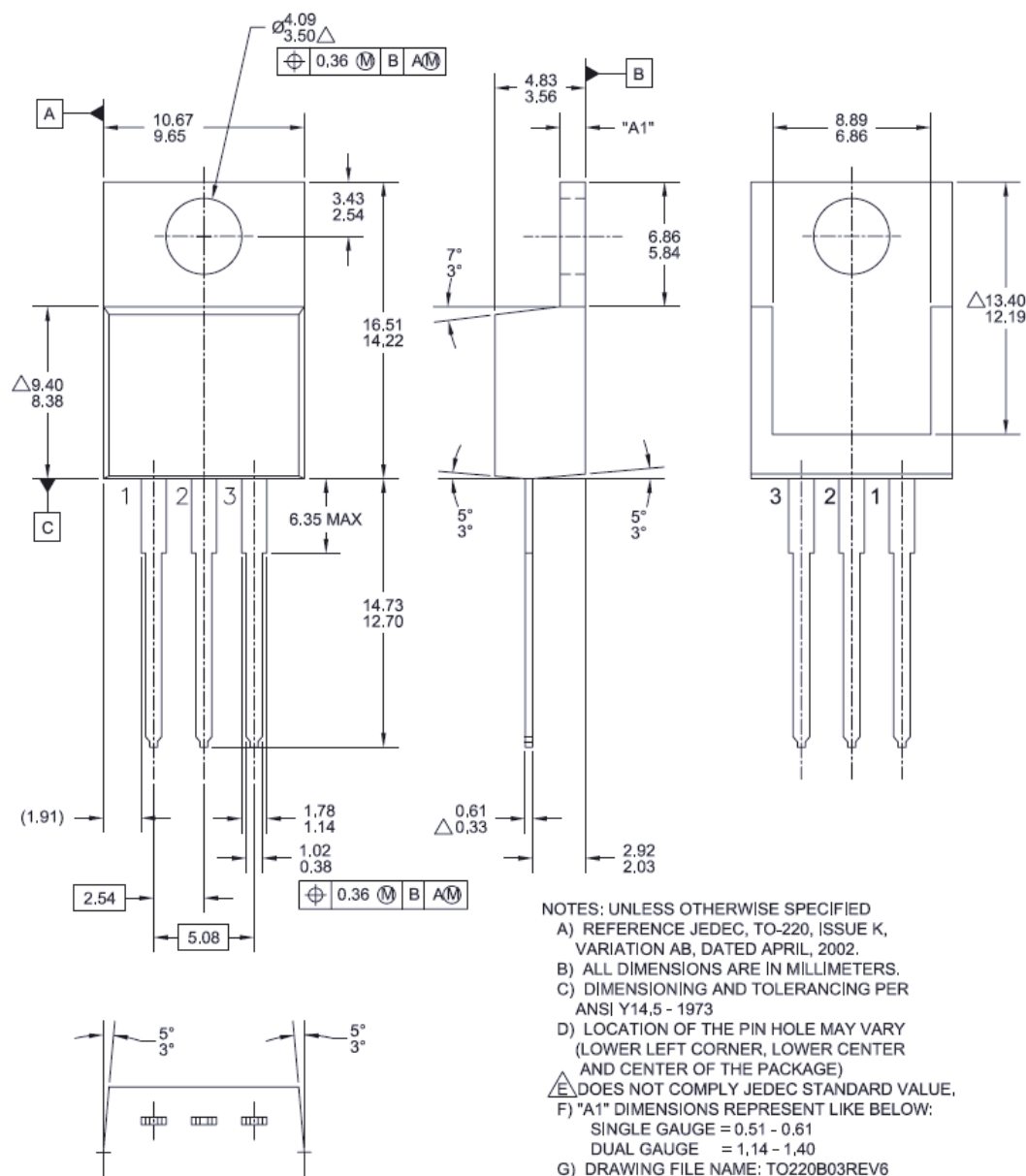


Figure 19. TO-220, Molded, 3-Lead, Jedec Variation AB

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Mechanical Dimensions

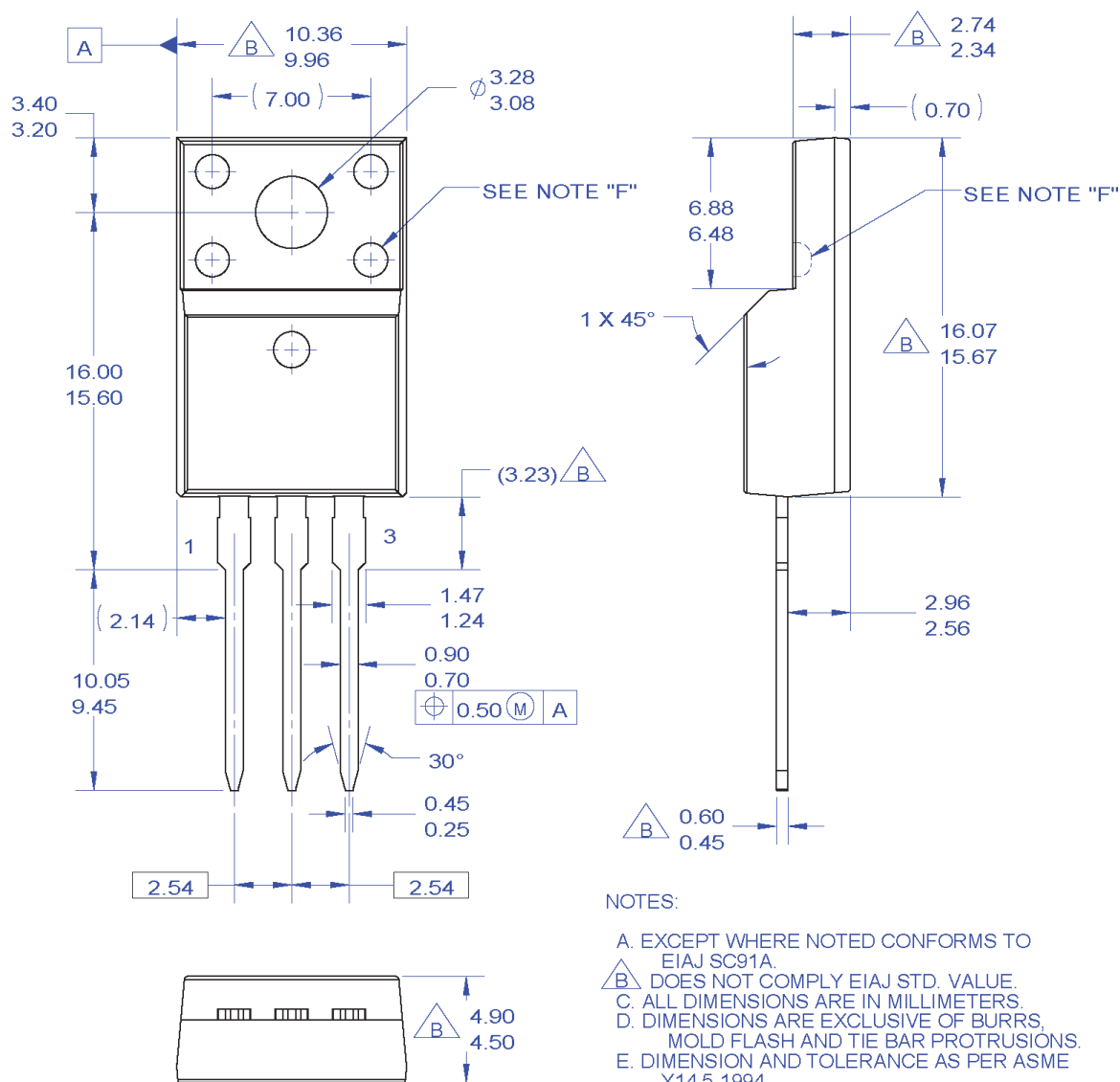


Figure 20. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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